

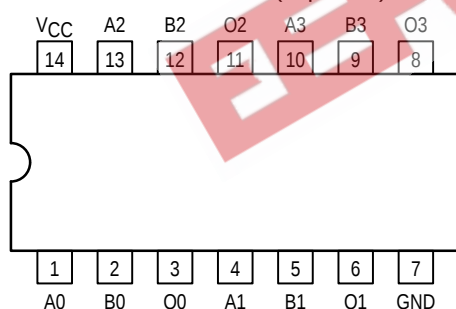
## Low-Voltage CMOS Quad 2-Input XOR Gate With 5V-Tolerant Inputs

The MC74LCX86 is a high performance, quad 2-input XOR gate operating from a 2.7 to 3.6V supply. High impedance TTL compatible inputs significantly reduce current loading to input drivers while TTL compatible outputs offer improved switching noise performance. A  $V_I$  specification of 5.5V allows MC74LCX86 inputs to be safely driven from 5V devices.

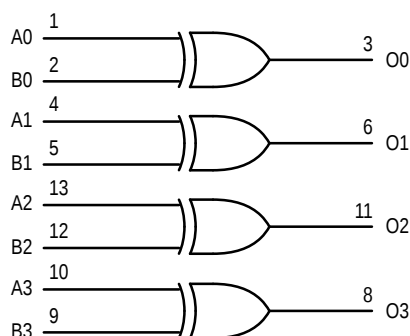
Current drive capability is 24mA at the outputs.

- Designed for 2.7 to 3.6V  $V_{CC}$  Operation
- 5V Tolerant Inputs — Interface Capability With 5V TTL Logic
- LVTTTL Compatible
- LVCMOS Compatible
- 24mA Balanced Output Sink and Source Capability
- Near Zero Static Supply Current (10 $\mu$ A) Substantially Reduces System Power Requirements
- Latchup Performance Exceeds 500mA
- ESD Performance: Human Body Model >2000V; Machine Model >200V

**Pinout: 14-Lead (Top View)**



**LOGIC DIAGRAM**



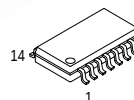
**MC74LCX86**

**LCX**

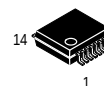
**LOW-VOLTAGE CMOS  
QUAD 2-INPUT XOR GATE**



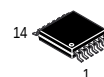
**D SUFFIX**  
PLASTIC SOIC  
CASE 751A-03



**M SUFFIX**  
PLASTIC SOIC EIAJ  
CASE 965-01



**SD SUFFIX**  
PLASTIC SSOP  
CASE 940A-03



**DT SUFFIX**  
PLASTIC TSSOP  
CASE 948G-01

**PIN NAMES**

| Pins   | Function    |
|--------|-------------|
| An, Bn | Data Inputs |
| On     | Outputs     |

**FUNCTION TABLE**

| Inputs |    | Outputs |
|--------|----|---------|
| An     | Bn | On      |
| L      | L  | L       |
| L      | H  | H       |
| H      | L  | H       |
| H      | H  | L       |



# MC74LCX86

## ABSOLUTE MAXIMUM RATINGS\*

| Symbol    | Parameter                        | Value                             | Condition      | Unit |
|-----------|----------------------------------|-----------------------------------|----------------|------|
| $V_{CC}$  | DC Supply Voltage                | -0.5 to +7.0                      |                | V    |
| $V_I$     | DC Input Voltage                 | $-0.5 \leq V_I \leq +7.0$         |                | V    |
| $V_O$     | DC Output Voltage                | $-0.5 \leq V_O \leq V_{CC} + 0.5$ | Note 1.        | V    |
| $I_{IK}$  | DC Input Diode Current           | -50                               | $V_I < GND$    | mA   |
| $I_{OK}$  | DC Output Diode Current          | -50                               | $V_O < GND$    | mA   |
|           |                                  | +50                               | $V_O > V_{CC}$ | mA   |
| $I_O$     | DC Output Source/Sink Current    | $\pm 50$                          |                | mA   |
| $I_{CC}$  | DC Supply Current Per Supply Pin | $\pm 100$                         |                | mA   |
| $I_{GND}$ | DC Ground Current Per Ground Pin | $\pm 100$                         |                | mA   |
| $T_{STG}$ | Storage Temperature Range        | -65 to +150                       |                | °C   |

\* Absolute maximum continuous ratings are those values beyond which damage to the device may occur. Exposure to these conditions or conditions beyond those indicated may adversely affect device reliability. Functional operation under absolute-maximum-rated conditions is not implied.

1. Output in HIGH or LOW State.  $I_O$  absolute maximum rating must be observed.

## RECOMMENDED OPERATING CONDITIONS

| Symbol              | Parameter                                                                       | Min                 | Typ | Max      | Unit |
|---------------------|---------------------------------------------------------------------------------|---------------------|-----|----------|------|
| $V_{CC}$            | Supply Voltage                                                                  | Operating           | 2.0 | 3.3      | V    |
|                     |                                                                                 | Data Retention Only | 1.5 | 3.3      |      |
| $V_I$               | Input Voltage                                                                   | 0                   |     | 5.5      | V    |
| $V_O$               | Output Voltage (HIGH or LOW State)                                              | 0                   |     | $V_{CC}$ | V    |
| $I_{OH}$            | HIGH Level Output Current, $V_{CC} = 3.0V - 3.6V$                               |                     |     | -24      | mA   |
| $I_{OL}$            | LOW Level Output Current, $V_{CC} = 3.0V - 3.6V$                                |                     |     | 24       | mA   |
| $I_{OH}$            | HIGH Level Output Current, $V_{CC} = 2.7V - 3.0V$                               |                     |     | -12      | mA   |
| $I_{OL}$            | LOW Level Output Current, $V_{CC} = 2.7V - 3.0V$                                |                     |     | 12       | mA   |
| $T_A$               | Operating Free-Air Temperature                                                  | -40                 |     | +85      | °C   |
| $\Delta t/\Delta V$ | Input Transition Rise or Fall Rate, $V_{IN}$ from 0.8V to 2.0V, $V_{CC} = 3.0V$ | 0                   |     | 10       | ns/V |

## DC ELECTRICAL CHARACTERISTICS

| Symbol   | Characteristic                     | Condition                                           | $T_A = -40^\circ\text{C to } +85^\circ\text{C}$ |      | Unit |
|----------|------------------------------------|-----------------------------------------------------|-------------------------------------------------|------|------|
|          |                                    |                                                     | Min                                             | Max  |      |
| $V_{IH}$ | HIGH Level Input Voltage (Note 2.) | $2.7V \leq V_{CC} \leq 3.6V$                        | 2.0                                             |      | V    |
| $V_{IL}$ | LOW Level Input Voltage (Note 2.)  | $2.7V \leq V_{CC} \leq 3.6V$                        |                                                 | 0.8  | V    |
| $V_{OH}$ | HIGH Level Output Voltage          | $2.7V \leq V_{CC} \leq 3.6V$ ; $I_{OH} = -100\mu A$ | $V_{CC} - 0.2$                                  |      | V    |
|          |                                    | $V_{CC} = 2.7V$ ; $I_{OH} = -12mA$                  | 2.2                                             |      |      |
|          |                                    | $V_{CC} = 3.0V$ ; $I_{OH} = -18mA$                  | 2.4                                             |      |      |
|          |                                    | $V_{CC} = 3.0V$ ; $I_{OH} = -24mA$                  | 2.2                                             |      |      |
| $V_{OL}$ | LOW Level Output Voltage           | $2.7V \leq V_{CC} \leq 3.6V$ ; $I_{OL} = 100\mu A$  |                                                 | 0.2  | V    |
|          |                                    | $V_{CC} = 2.7V$ ; $I_{OL} = 12mA$                   |                                                 | 0.4  |      |
|          |                                    | $V_{CC} = 3.0V$ ; $I_{OL} = 16mA$                   |                                                 | 0.4  |      |
|          |                                    | $V_{CC} = 3.0V$ ; $I_{OL} = 24mA$                   |                                                 | 0.55 |      |

2. These values of  $V_I$  are used to test DC electrical characteristics only.

## DC ELECTRICAL CHARACTERISTICS (continued)

| Symbol           | Characteristic                        | Condition                                                               | T <sub>A</sub> = -40°C to +85°C |      | Unit |
|------------------|---------------------------------------|-------------------------------------------------------------------------|---------------------------------|------|------|
|                  |                                       |                                                                         | Min                             | Max  |      |
| I <sub>I</sub>   | Input Leakage Current                 | 2.7V ≤ V <sub>CC</sub> ≤ 3.6V; 0V ≤ V <sub>I</sub> ≤ 5.5V               |                                 | ±5.0 | μA   |
| I <sub>CC</sub>  | Quiescent Supply Current              | 2.7V ≤ V <sub>CC</sub> ≤ 3.6V; V <sub>I</sub> = GND or V <sub>CC</sub>  |                                 | 10   | μA   |
|                  |                                       | 2.7V ≤ V <sub>CC</sub> ≤ 3.6V; 3.6V ≤ V <sub>I</sub> ≤ 5.5V             |                                 | ±10  | μA   |
| ΔI <sub>CC</sub> | Increase in I <sub>CC</sub> per Input | 2.7V ≤ V <sub>CC</sub> ≤ 3.6V; V <sub>IH</sub> = V <sub>CC</sub> - 0.6V |                                 | 500  | μA   |

AC CHARACTERISTICS (t<sub>R</sub> = t<sub>F</sub> = 2.5ns; C<sub>L</sub> = 50pF; R<sub>L</sub> = 500Ω)

| Symbol                                 | Parameter                            | Waveform | Limits                          |            |                        | Unit |
|----------------------------------------|--------------------------------------|----------|---------------------------------|------------|------------------------|------|
|                                        |                                      |          | T <sub>A</sub> = -40°C to +85°C |            |                        |      |
|                                        |                                      |          | V <sub>CC</sub> = 3.0V to 3.6V  |            | V <sub>CC</sub> = 2.7V |      |
|                                        |                                      |          | Min                             | Max        | Max                    |      |
| t <sub>PLH</sub><br>t <sub>PHL</sub>   | Propagation Delay<br>Input to Output | 1,2      | 1.5<br>1.5                      | 6.5<br>6.5 | 7.0<br>7.0             | ns   |
| t <sub>OSHL</sub><br>t <sub>OSLH</sub> | Output-to-Output Skew<br>(Note 3.)   |          |                                 | 1.0<br>1.0 |                        | ns   |

3. Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t<sub>OSHL</sub>) or LOW-to-HIGH (t<sub>OSLH</sub>); parameter guaranteed by design.

## DYNAMIC SWITCHING CHARACTERISTICS

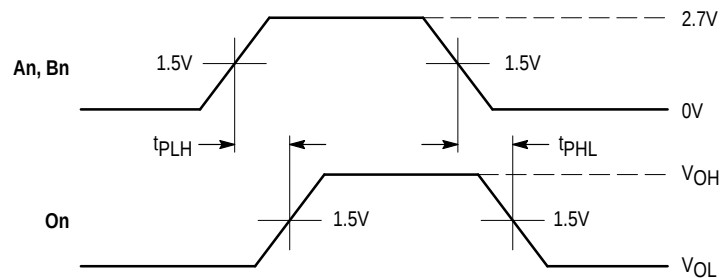
| Symbol           | Characteristic                       | Condition                                                                                   | T <sub>A</sub> = +25°C |     |     | Unit |
|------------------|--------------------------------------|---------------------------------------------------------------------------------------------|------------------------|-----|-----|------|
|                  |                                      |                                                                                             | Min                    | Typ | Max |      |
| V <sub>OLP</sub> | Dynamic LOW Peak Voltage (Note 4.)   | V <sub>CC</sub> = 3.3V, C <sub>L</sub> = 50pF, V <sub>IH</sub> = 3.3V, V <sub>IL</sub> = 0V |                        | 0.8 |     | V    |
| V <sub>OLV</sub> | Dynamic LOW Valley Voltage (Note 4.) | V <sub>CC</sub> = 3.3V, C <sub>L</sub> = 50pF, V <sub>IH</sub> = 3.3V, V <sub>IL</sub> = 0V |                        | 0.8 |     | V    |

4. Number of outputs defined as "n". Measured with "n-1" outputs switching from HIGH-to-LOW or LOW-to-HIGH. The remaining output is measured in the LOW state.

## CAPACITIVE CHARACTERISTICS

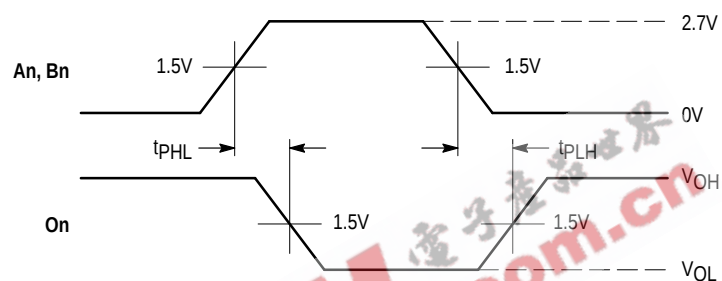
| Symbol           | Parameter                     | Condition                                                             | Typical | Unit |
|------------------|-------------------------------|-----------------------------------------------------------------------|---------|------|
| C <sub>IN</sub>  | Input Capacitance             | V <sub>CC</sub> = 3.3V, V <sub>I</sub> = 0V or V <sub>CC</sub>        | 7       | pF   |
| C <sub>OUT</sub> | Output Capacitance            | V <sub>CC</sub> = 3.3V, V <sub>I</sub> = 0V or V <sub>CC</sub>        | 8       | pF   |
| C <sub>PD</sub>  | Power Dissipation Capacitance | 10MHz, V <sub>CC</sub> = 3.3V, V <sub>I</sub> = 0V or V <sub>CC</sub> | 25      | pF   |

## MC74LCX86



**WAVEFORM 1 – NON-INVERTING PROPAGATION DELAYS**

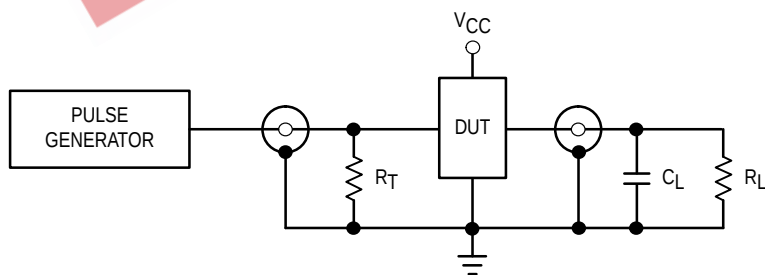
$t_P = t_F = 2.5\text{ns}$ , 10% to 90%;  $f = 1\text{MHz}$ ;  $t_W = 500\text{ns}$



**WAVEFORM 2 – INVERTING PROPAGATION DELAYS**

$t_P = t_F = 2.5\text{ns}$ , 10% to 90%;  $f = 1\text{MHz}$ ;  $t_W = 500\text{ns}$

**Figure 1. AC Waveforms**



$C_L = 50\text{pF}$  or equivalent (Includes jig and probe capacitance)

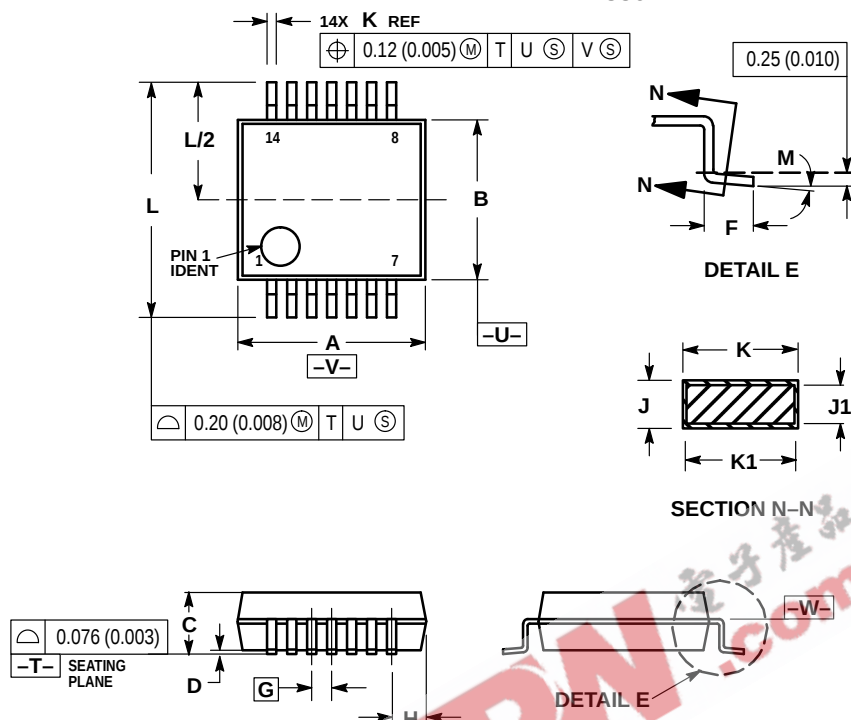
$R_L = R_1 = 500\Omega$  or equivalent

$R_T = Z_{OUT}$  of pulse generator (typically  $50\Omega$ )

**Figure 2. Test Circuit**

## OUTLINE DIMENSIONS

**SD SUFFIX**  
**PLASTIC SSOP PACKAGE**  
CASE 940A-03  
ISSUE B

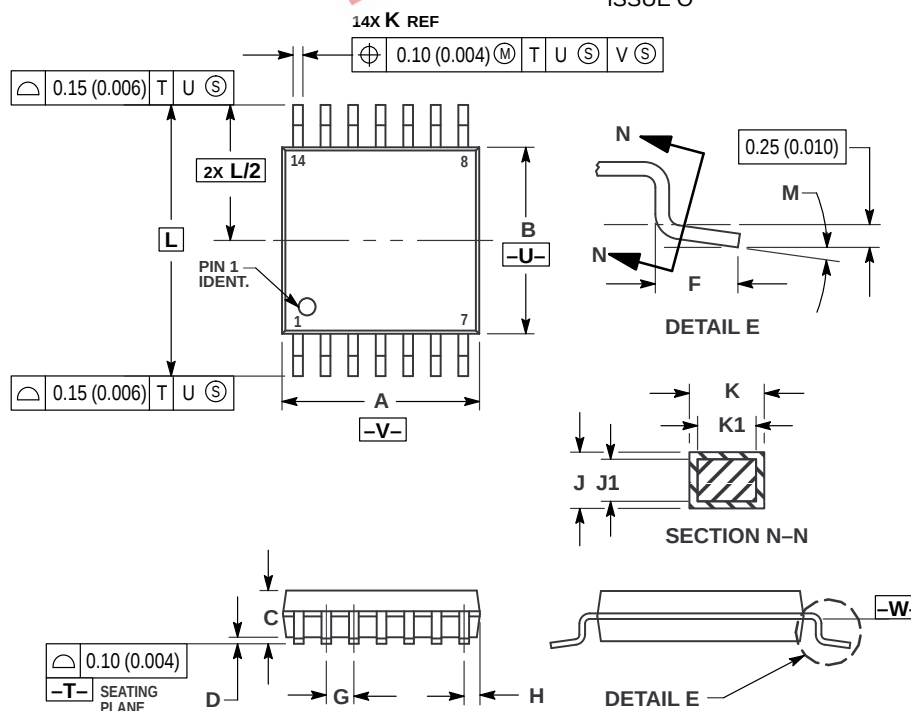


## NOTES:

- 1 DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- 2 CONTROLLING DIMENSION: MILLIMETER.
- 3 DIMENSION A DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
- 4 DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
- 5 DIMENSION K DOES NOT INCLUDE DAMBAR PROTRUSION/INTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.13 (0.005) TOTAL IN EXCESS OF K DIMENSION AT MAXIMUM MATERIAL CONDITION. DAMBAR INTRUSION SHALL NOT REDUCE DIMENSION K BY MORE THAN 0.07 (0.002) AT LEAST MATERIAL CONDITION.
- 6 TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.
- 7 DIMENSION A AND B ARE TO BE DETERMINED AT DATUM PLANE -W-.

| DIM | MILLIMETERS |      | INCHES    |       |
|-----|-------------|------|-----------|-------|
|     | MIN         | MAX  | MIN       | MAX   |
| A   | 6.07        | 6.33 | 0.238     | 0.249 |
| B   | 5.20        | 5.38 | 0.205     | 0.212 |
| C   | 1.73        | 1.99 | 0.068     | 0.078 |
| D   | 0.05        | 0.21 | 0.002     | 0.008 |
| F   | 0.63        | 0.95 | 0.024     | 0.037 |
| G   | 0.65 BSC    |      | 0.026 BSC |       |
| H   | 1.08        | 1.22 | 0.042     | 0.048 |
| J   | 0.09        | 0.20 | 0.003     | 0.008 |
| J1  | 0.09        | 0.16 | 0.003     | 0.006 |
| K   | 0.25        | 0.38 | 0.010     | 0.015 |
| K1  | 0.25        | 0.33 | 0.010     | 0.013 |
| L   | 7.65        | 7.90 | 0.301     | 0.311 |
| M   | 0°          | 8°   | 0°        | 8°    |

**DT SUFFIX**  
**PLASTIC TSSOP PACKAGE**  
CASE 948G-01  
ISSUE O

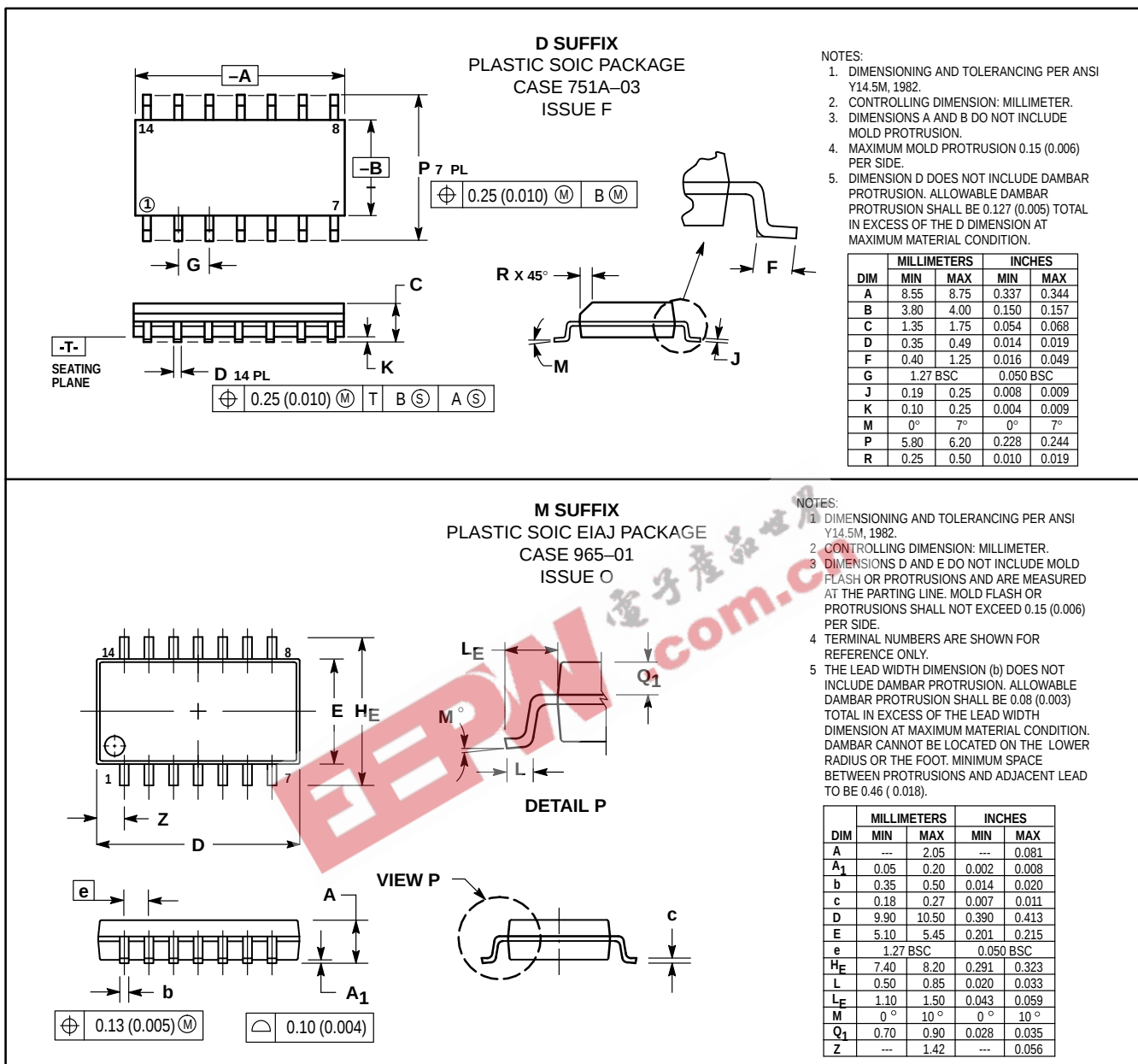


## NOTES:

- 1 DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- 2 CONTROLLING DIMENSION: MILLIMETER.
- 3 DIMENSION A DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
- 4 DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE.
- 5 DIMENSION K DOES NOT INCLUDE DAMBAR PROTRUSION/INTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE K DIMENSION AT MAXIMUM MATERIAL CONDITION.
- 6 TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.
- 7 DIMENSION A AND B ARE TO BE DETERMINED AT DATUM PLANE -W-.

| DIM | MILLIMETERS |      | INCHES    |       |
|-----|-------------|------|-----------|-------|
|     | MIN         | MAX  | MIN       | MAX   |
| A   | 4.90        | 5.10 | 0.193     | 0.200 |
| B   | 4.30        | 4.50 | 0.169     | 0.177 |
| C   | —           | 1.20 | —         | 0.047 |
| D   | 0.05        | 0.15 | 0.002     | 0.006 |
| F   | 0.50        | 0.75 | 0.020     | 0.030 |
| G   | 0.65 BSC    |      | 0.026 BSC |       |
| H   | 0.50        | 0.60 | 0.020     | 0.024 |
| J   | 0.09        | 0.20 | 0.004     | 0.008 |
| J1  | 0.09        | 0.16 | 0.004     | 0.006 |
| K   | 0.19        | 0.30 | 0.007     | 0.012 |
| K1  | 0.19        | 0.25 | 0.007     | 0.010 |
| L   | 6.40 BSC    |      | 0.252 BSC |       |
| M   | 0°          | 8°   | 0°        | 8°    |

## OUTLINE DIMENSIONS



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